


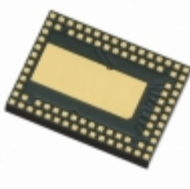
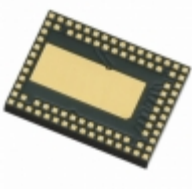





	<h2 style="color: red;">SI1034X-T1-GE3</h2>	
	Hersteller-Teilenummer:	SI1034X-T1-GE3
	Hersteller / Marke:	Vishay / Siliconix
	Teil der Beschreibung:	MOSFET 2N-CH 20V 0.18A SC89-6
Datenblätter:	 SI1034X-T1-GE3.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 91308 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	SI1034X-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 20V 0.18A SC89-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	91308 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	180mA
Rds On (Max) @ Id, Vgs	5 Ohm @ 200mA, 4.5V
VGS (th) (Max) @ Id	1.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)

SI1034X-T1-GE3 ist neu im Original, Suche SI1034X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1034X-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1034X-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1035X-T1 VISHAY SI1035X-T1 VISHAY</p>	 <p>SI1035-B-GM3R Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1035-B-GM3 Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1034X-T1-E3 Vishay / Siliconix MOSFET 2N-CH 20V 0.18A SOT563F</p>
 <p>SI1035-A-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1035-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1034X-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 0.18A SOT563F</p>	 <p>SI1034X-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 0.18A SC89-6</p>

heiße Teile

Mehr

⊗ SI1031R-T1-GE3	↔ SI1031R-T1-GE3	⇒ SI1031X-T1	D SI1031X-T1-E3	↔ SI1031X-T1-E3
⊣ SI1031X-T1-GE3	⊗ SI1031X-T1-GE3	D SI1032R-T1	⇒ SI1032R-T1-E3	↔ SI1032R-T1-E3
⊗ SI1032R-T1-GE3	⊣ SI1032R-T1-GE3	⊗ SI1032X-T1	↔ SI1032X-T1-E3	↔ SI1032X-T1-E3
D SI1032X-T1-GE3	⊗ SI1032X-T1-GE3	⊣ SI1033X-T1	⊗ SI1033X-T1-E3	↔ SI1033X-T1-E3
⇒ SI1034CX-T1-GE3	↔ SI1034CX-T1-GE3	⊗ SI1034X-T1	⊣ SI1034X-T1-E3	↔ SI1034X-T1-E3
↔ SI1034X-T1-GE3	⇒ SI1035X-T1	D SI1035X-T1-E3	⊗ SI1035X-T1-E3	⊣ SI1035X-T1-GE3
⊗ SI1035X-T1-GE3	D SI1039X-T1-E3	⇒ SI1039X-T1-E3	↔ SI1040X-T1-E3	↔ SI1040X-T1-E3
⊣ SI1040X-T1-GE3	⊗ SI1040X-T1-GE3	↔ SI1041ADY	⇒ SI1041DY-T1	↔ SI1041DY-T1-E3
⊗ SI1045AB	⊣ SI1045ADY-T1	⊗ Si1046X-T1-E3	D SI1046X-T1-GE3	↔ SI1046X-T1-GE3
↔ SI1050X-T1-E3	⊗ SI1050X-T1-E3	⊣ SI1050X-T1-GE3	⊗ SI1050X-T1-GE3	↔ SI1051X-T1-GE3

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